NSN 5962-01-143-1733

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 0.880 inches and 0.920 inches
Body Width:
Between 0.265 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.165 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-10.0/+85.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Static operation and high speed and hermetically sealed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
15 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
85.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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